

## MOS FIELD EFFECT TRANSISTOR

2SK2070

### N-CHANNEL MOS FET FOR HIGH-SPEED SWITCHING

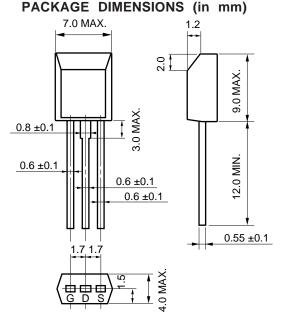
The 2SK2070 is a N-channel MOS FET of a vertical type and is a switching element that can be directly driven by the output of an IC operating at 5 V.

This product has a low ON resistance and superb switching characteristics and is ideal for driving the actuators, such as motors and DC/DC converters.

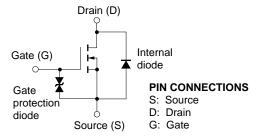
#### **FEATURES**

- New package intermediate between small-signal and power models
- Can be directly driven by output of 5-V IC
- · Low ON resistance

 $R_{DS(on)} = 0.45~\Omega~MAX.~@V_{GS} = 4~V,~I_{D} = 1.0~A$   $R_{DS(on)} = 0.35~\Omega~MAX.~@V_{GS} = 10~V,~I_{D} = 1.0~A$ 



#### **EQUIVALENT CIRCUIT**



#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

PARAMETER	SYMBOL	TEST CONDITIONS	RATING	UNIT
Drain to Source Voltage	Voss	Vgs = 0	100	V
Gate to Source Voltage	Vgss	V <sub>DS</sub> = 0	±20	V
Drain Current (DC)	I <sub>D(DC)</sub>		±1.5	Α
Drain Current (Pulse)	I <sub>D</sub> (pulse)	PW ≤ 10 ms,	±3.0	А
		Duty cycle ≤ 50 %		
Total Power Dissipation	Рт		1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C



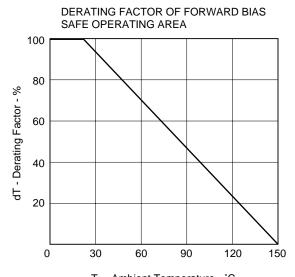
# ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-Off Current	IDSS	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0			1.0	μΑ
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0			±10	μΑ
Gate Cut-Off Voltage	Vgs(off)	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	0.8	1.2	2.0	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 A	2.0			S
Drain to Source On-State Resistance	RDS(on)1	Vgs = 4 V, ID = 1.0 A		0.28	0.45	Ω
Drain to Source On-State Resistance	RDS(on)2	Vos = 10 V, ID = 1.0 A		0.24	0.35	Ω
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0,		530		pF
Output Capacitance	Coss	f = 1.0 MHz		150		pF
Reverse Transfer Capacitance	Crss			30		pF
Turn-On Delay Time	td(on)	V <sub>DD</sub> = 10 V, I <sub>D</sub> = 1.0 A		5		ns
Rise Time	tr	$V_{GS(on)}$ = 10 V, $R_G$ = 10 $\Omega$		50		ns
Turn-Off Delay Time	td(off)	R <sub>L</sub> = 10 Ω		90		ns
Fall Time	tr			15		ns

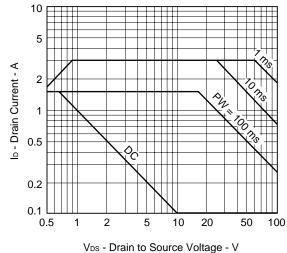
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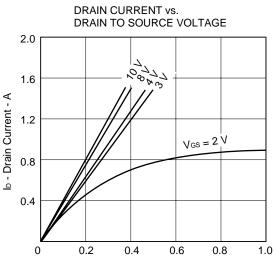
#### TYPICAL CHARACTERISTICS (TA = 25 °C)



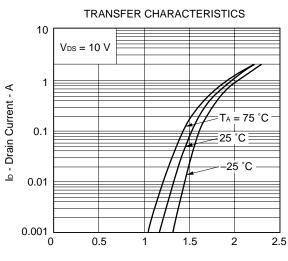
TA - Ambient Temperature - °C



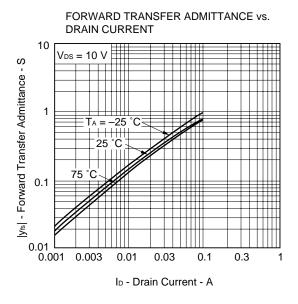
FORWARD BIAS SAFE OPERATING AREA

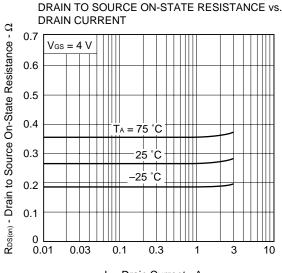


V<sub>DS</sub> - Drain to Source Voltage - V



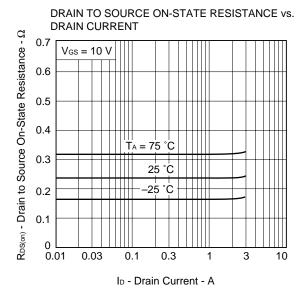
V<sub>GS</sub> - Gate to Source Voltage - V

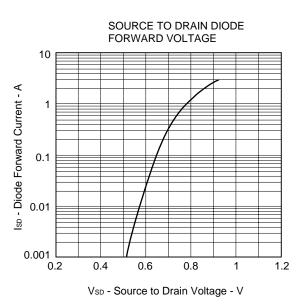


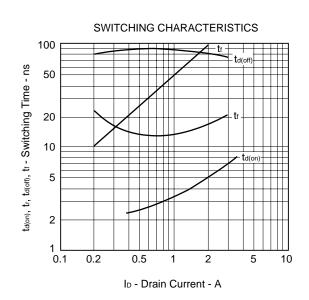


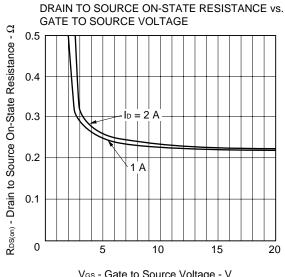
ID - Drain Current - A



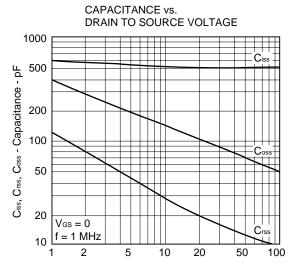








V<sub>GS</sub> - Gate to Source Voltage - V



V<sub>DS</sub> - Drain to Source Voltage - V



## REFERENCE

Document Name	Document No.		
NEC semiconductor device reliability/quality control system	TEI-1202		
Quality grade on NEC semiconductor devices	IEI-1209		
Semiconductor device mounting technology manual	C10535E		
Guide to quality assurance for semiconductor devices	MEI-1202		
Semiconductor selection guide	X10679E		

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Anti-radioactive design is not implemented in this product.